

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1032	(257/43).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/16 18:09
S11 1	52	(hoffman near3 randy).in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 16:38
S10 9	10	amorphous adj2 (TCO transparent adj conductive adj oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 15:43
S38	76	S37 and (@ad<"20040312" @rlad<"20040312")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 15:42
S10 4	2	"a-TCO"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 15:41
S10 3	7	TFT and transparent adj gate and transparent adj (source drain) and ("a-Si" amorphous adj (Si silicon))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 15:40
S10 0	13	S95 and TFT and transparent near2 gate and transparent near2 (source drain) and amorphous adj (Si silicon)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 13:51
S10 2	13	(S94 S95) and transparent adj TFT	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 13:40
S10 1	7	S100 and @pd<"20030312"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 13:40

EAST Search History

S97	527	S96 and @pd<"20030312"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 13:26
S96	1265	S95 and TFT and ITO	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 13:25
S99	161	(257/63).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/16 13:17
S98	480	S97 and amorphous	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 13:17
S95	2469	(257/59).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/16 13:08
S94	803	(257/57).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/16 13:06
S75	100	S71 and amorphous	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/16 13:06
S93	188	S92 and (@ad<"20040312" @rlad<"20040312")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/15 16:31
S82	467	S81 and (@ad<"20040312" @rlad<"20040312")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/15 16:31

EAST Search History

S92	243	(InGaZnO GaInZnO ZnO metal adj oxide) near3 amorphous and (TFT transistor MOSFET MOS! adj (transistor FET))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/15 16:30
S81	564	(InGaZnO GaInZnO ZnO metal adj oxide) near3 amorphous and (TFT transistor MOSFET MOS)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/15 16:29
S89	3	("6727522").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/15 16:18
S39	206	S36 and (@ad<"20040312" @rlad<"20040312")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/15 14:38
S46	0	(InGaZnO GaInZnO) and (TFT transistor MOSFET MOS)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/15 14:37